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	Applicati n No.	Applicant(s)	
	10/611,898	YOO ET AL.	
Notice of Allowability	Examiner	Art Unit	
	Asok K. Sarkar	2829	
The MAILING DATE of this communication appeal claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this or other appropriate communica GHTS. This application is subjection	application. If not include tion will be mailed in due of	d course. <b>THIS</b>
1. X This communication is responsive to Application filed 7/3/2	<u>0003</u> .		
2. ⊠ The allowed claim(s) is/are <u>1-10</u> .			
3. $igotimes$ The drawings filed on <u>03 July 2003</u> are accepted by the Ex	aminer.		
4.  Acknowledgment is made of a claim for foreign priority una)  All b)  Some* c)  None of the:  1.  Certified copies of the priority documents have 2.  Certified copies of the priority documents have 3.  Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)).  * Certified copies not received:  Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.  5.  A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give 6.  CORRECTED DRAWINGS ( as "replacement sheets") must be comply including changes required by the Notice of Draftspers	e been received. e been received in Application Note the communication to file a reserved in the second sec	his national stage applicated the ply complying with the requestion of the plant of Notice and the pla	uirements
1) hereto or 2) to Paper No./Mail Date(b) including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in th		hack) of
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	he header according to 37 CFR 1.1	21(d).	Dacky Of
7. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT	sit of BIOLOGICAL MATERIA FOR THE DEPOSIT OF BIOLOG	AL must be submitted. N SICAL MATERIAL.	lote the
<ul> <li>Attachment(s)</li> <li>1.  Notice of References Cited (PTO-892)</li> <li>2.  Notice of Draftperson's Patent Drawing Review (PTO-948)</li> <li>3.  Information Disclosure Statements (PTO-1449 or PTO/SB/O Paper No./Mail Date</li></ul>	6. ☐ Interview Summ Paper No./Mail 08), 7. ⊠ Examiner's Ame	Date .	

## DETAILED ACTION

## **EXAMINER'S AMENDMENT**

- 1. The Applicant's representative was contacted in order to amend the abstract to reduce its size below 150 words and to rewrite the step (b) of claim 1 in order to clearly state the limitations of the step.
- 2. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Benjamin Hauptman on June 9, 2004.

The application has been amended as follows:

In the Abstract, in line 2, following the word 'diodes', delete "is provided. The method comprises the steps of, " and insert - - starts by - - .

Replace claim 1 with the attached copy of the new version of claim 1.

## Allowable Subject Matter

- 3. Claims 1 10 are allowed.
- 4. The following is an examiner's statement of reasons for allowance:

Claims 1 - 10 recite, inter alia, a method of manufacturing GaN light emitting diodes comprising the steps of partially cutting the light emitting structure formed on a substrate into plural units so that at least approximately 100 Å of the thickness of the first conductive GaN clad layer remains on the substrate, attaching a conductive

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substrate to exposed upper surfaces of the unit light emitting structures using a conductive adhesive layer, irradiating a laser beam on the sapphire substrate to remove the sapphire substrate from the unit light emitting structures, wherein the residual first conductive GaN clad layer is removed so that the light emitting structure can be perfectly divided into the unit light emitting structures with a size same as that of light emitting diodes to be finally manufactured, forming contacts and cutting the resulting structure along the cut lines of the unit light emitting structures into plural unit light emitting diodes. Although, Kelly, US 6,559,075 teaches a method of separating the substrate from a GaN LED device by illuminating with an electromagnetic radiation, attaching a conductive substrate and applying contacts on both sides, he fails to teach the step of partially cutting the structure before attaching the second substrate and completely separating the LEDs after applying the contacts on both sides of the devices. Additionally, the art of record does not disclose or anticipate the above limitation in combination with other claim elements nor would it be obvious to modify the art of record so as to form a device including the above limitation.

## Conclusion

5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Shakuda, US 5,557,115; Yamamoto, US 5,994,205; Haerie, US 6,100,104; Ishida, US 6,562,701; Liu, US 6,665,820 and Ogawa, US 22002/0182839 teach methods for fabricating GaN LEDs.

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6. Any comments considered necessary by applicant must be submitted no later

than the payment of the issue fee and, to avoid processing delays, should preferably

accompany the issue fee. Such submissions should be clearly labeled "Comments on

Statement of Reasons for Allowance."

7. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Asok K. Sarkar whose telephone number is 571 272

1970. The examiner can normally be reached on Monday - Friday (8 AM- 5 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Kammie Cuneo can be reached on 571 272 1957. The fax phone number

for the organization where this application or proceeding is assigned is 703-872-9306.

8. Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

Asok K. Sarkar June 10, 2004

Patent Examiner

SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800